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February 2020

Changing the World's Energy Future

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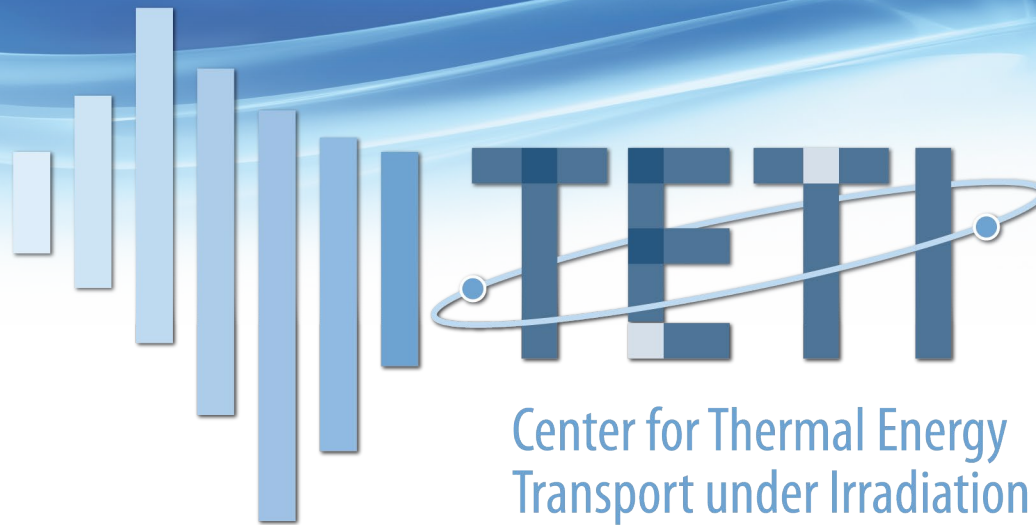
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**Prepared for the
U.S. Department of Energy
Under DOE Idaho Operations Office
Contract DE-AC07-05ID14517**



Center for Thermal Energy
Transport under Irradiation

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Y. Wang², T. Yao¹, L. He¹, J.M. Mann³, A. El-Azab⁴, J. Gan¹, D.H. Hurley¹



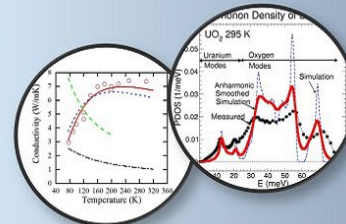
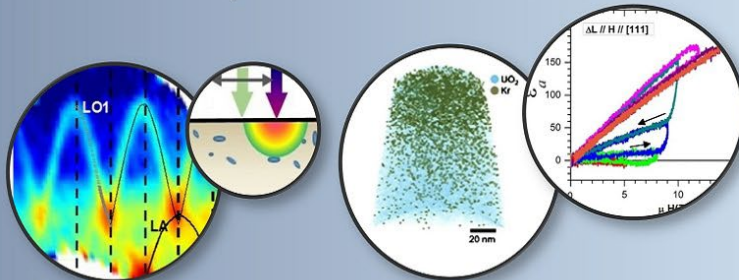
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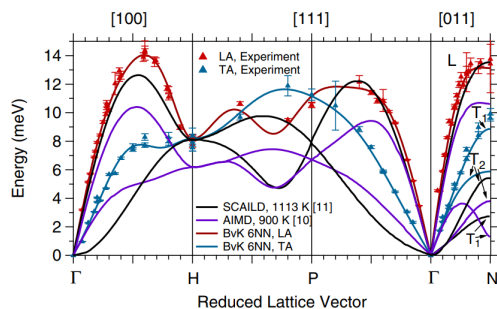
Tailored Properties in Advanced Nuclear Fuels



First principles understanding of electron and phonon transport in 5f electron materials in extreme irradiation environments

Science Question 1

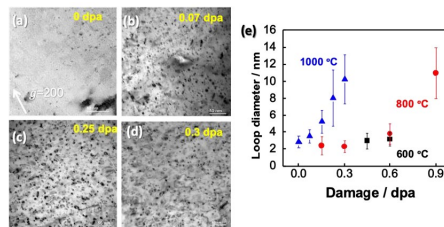
What is the impact of 5f electrons on phonon and electron structure in $Th_{1-x}U_xO_2$ and UZr alloys?



Brubaker, Z.E. et al., Phys. Rev. B. (2019)

Science Question 2

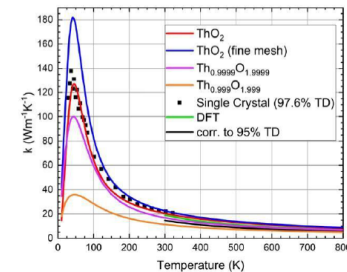
How do intrinsic and irradiation-induced defects self-organize in $Th_{1-x}U_xO_2$ and UZr alloys, and what are their impacts on electron and phonon scattering?



Yao, T., et al., in prep. (2020)

Science Question 3

What are the collective effects of defects, defect ordering, and defect supersaturation on thermal transport of $Th_{1-x}U_xO_2$ and UZr alloys?



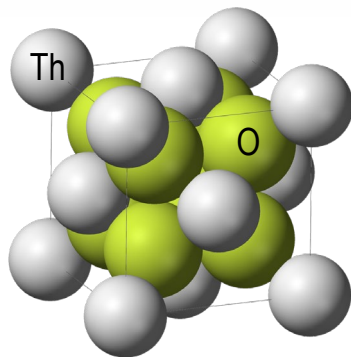
Deskins, R., et al., in prep. (2020)

Atom scale *Dynamic Mean Field Theory*
ARPES **First principles**
Quantum Oscillations
Neutron scattering *Defect free*

HRTEM Atom scale **Defects**
Electron and phonon scattering **Input**
Atom probe tomography

Modulated thermoreflectance *Operando*
Thermal conductivity *Output*
Mesoscale complexity **Boltzmann**

Thorium Dioxide Crystal Structure and Synthesis

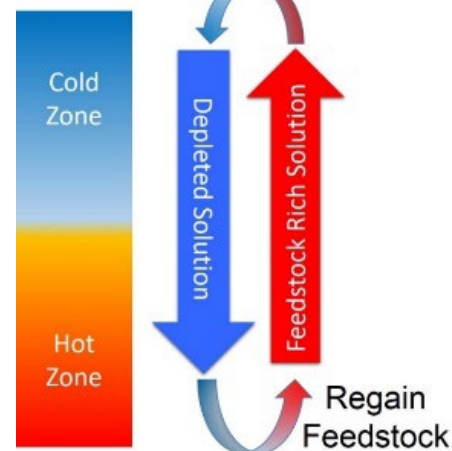


Physical Properties

Elastic Constants [§]	$C_{11} = 367 \text{ GPa}$ $C_{12} = 106 \text{ GPa}$ $C_{44} = 79.7 \text{ GPa}$
Density [¶]	10.01 g/cm ³
Melting Point [‡]	3,350° C
Boiling Point [‡]	4,400° C
Molar Mass	264.037 g/mol
Refractive Index (n) [¶]	2.105 (at 589.3 nm) 2.135 (at 435.8 nm)

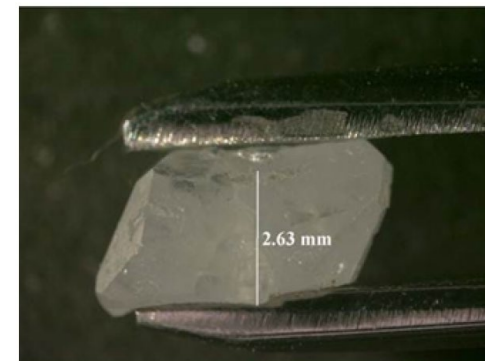
Crystallization
Zone
(690 °C)

Feedstock
Zone
(750 °C)



Hydrothermal Crystal Synthesis Method

- Spontaneous nucleation performed in silver ampoules
- ThO₂ feedstock powder placed in silver ampoule
- 6M CsF mineralizer solution used to dissolve feedstock and transport it to crystallization zone
- Water counter-pressure applied to silver ampoule
- Reaction conditions maintained for 10 days



[§] P. Macedo, W. Capps, J. Wachtmann/ J. Amer. Ceram. Soc. (1964)

[¶] J. Belle, R.M. Berman, DOE/NE—0060, (1984)

[‡] W.M. Haynes, Handbook of Chemistry and Physics (92nd ed.). (2011)

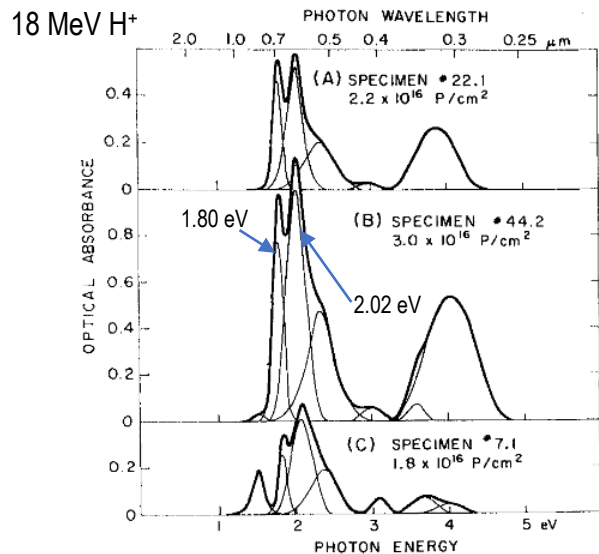
Ion Irradiation at Texas A&M Accelerator Laboratory



Sample ID	Avg. dpa in Plateau Region (0 – 12.5 μm)	H ⁺ ion energy	H ⁺ ion irradiation fluence (ions/cm ²)	Irradiation Temperature
ThO2-SN-8f	Pristine	N/A	N/A	N/A
ThO2-SN-8h	0.01 dpa	2 MeV	1.73×10^{17}	Room Temperature
ThO2-SN-8j	0.05 dpa	2 MeV	8.635×10^{17}	Room Temperature
ThO2-SN-8c	0.1 dpa	2 MeV	1.73×10^{18}	Room Temperature

Changes in Optical Absorption after Ion Irradiation

- Proton irradiation changed thorium dioxide a colorless crystal to a dark blue appearance
- Change in optical absorption due to electrons trapped in point defects that create states within the bandgap



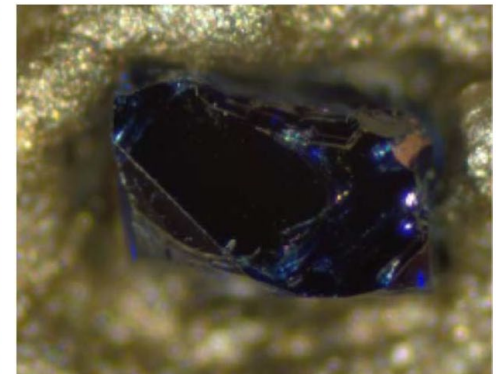
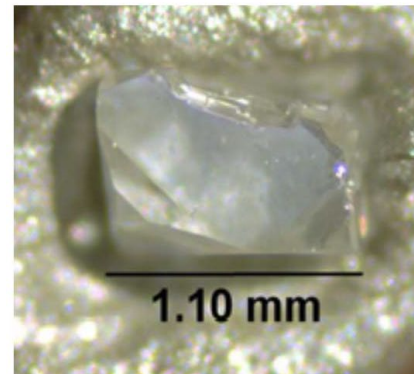
B.G. Childs, P.J. Harvey, and J.B. Hallett, Color centers and point defects in irradiated thorium.
J. Am. Cer. Soc., 53(8), 431-435 (1970).

Pre-Irradiation

Post-Irradiation

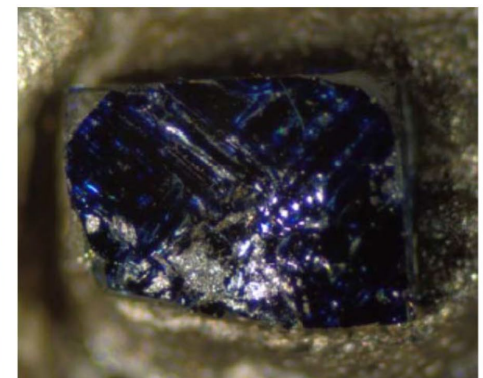
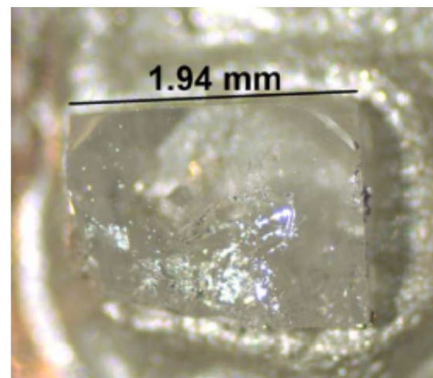
ThO₂-SN-8h

0.01 dpa
Avg. Plateau
Displacement
Damage

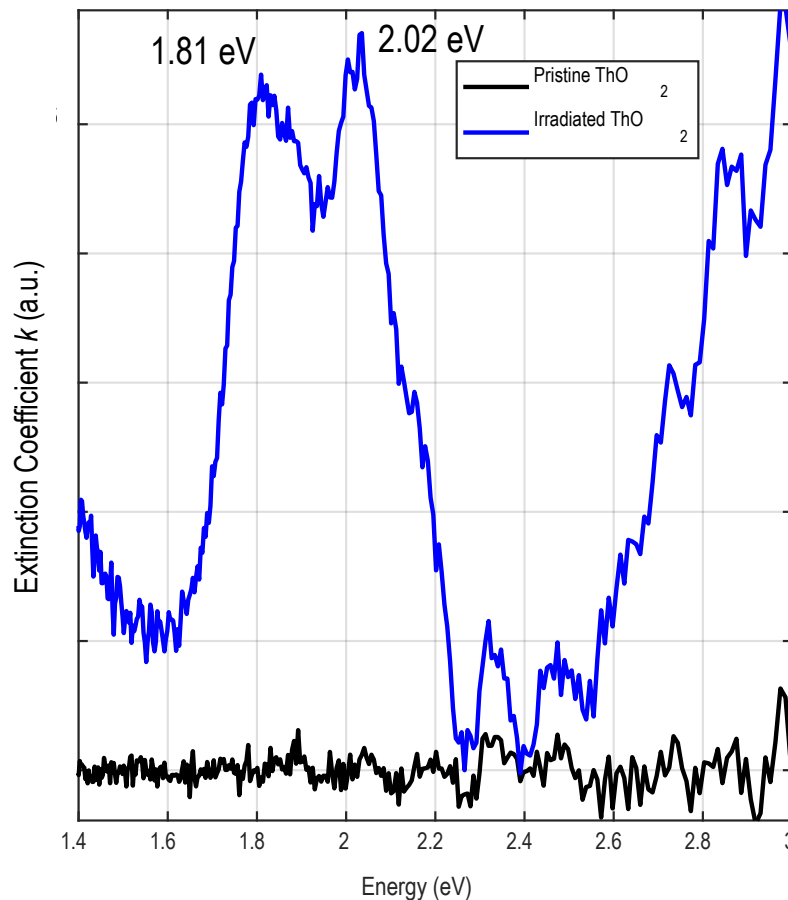


ThO₂-SN-8j

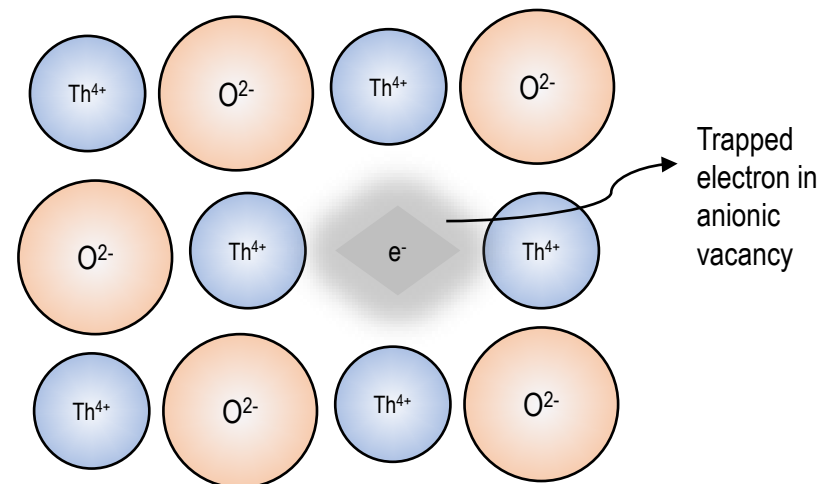
0.05 dpa
Avg. Plateau
Displacement
Damage



Characterization of Microstructural Damage via Optical Spectroscopy

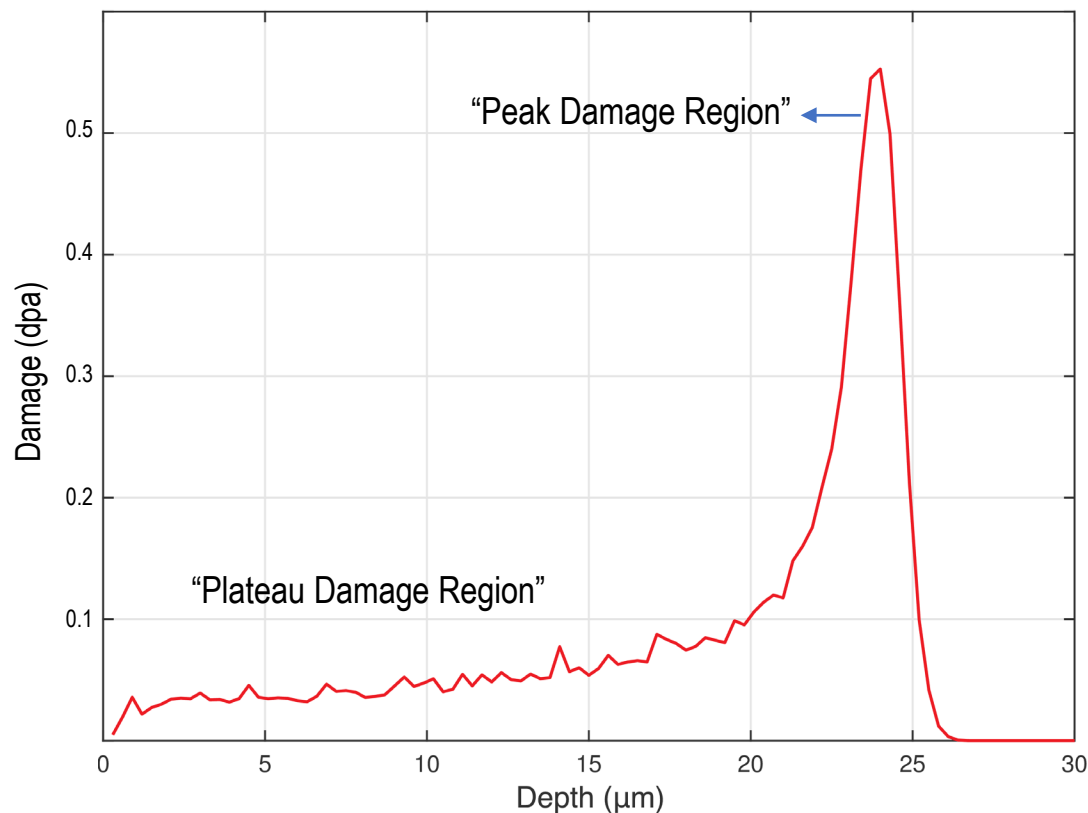


- Optical Absorption/ emission could be influenced by electronic transitions from intervalence bands created by irradiation-induced defects, or by charged defects
- Intensities of absorbed/ emitted spectra may be used to correlate with displacement damage levels

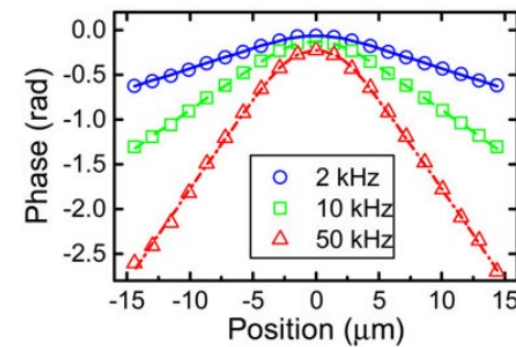
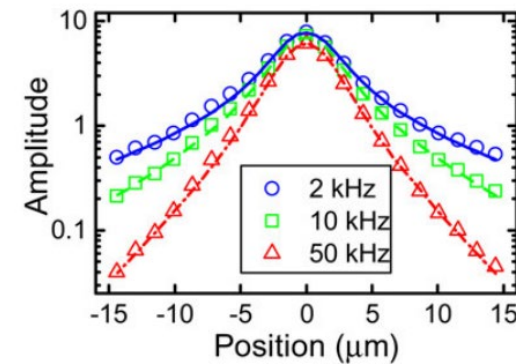
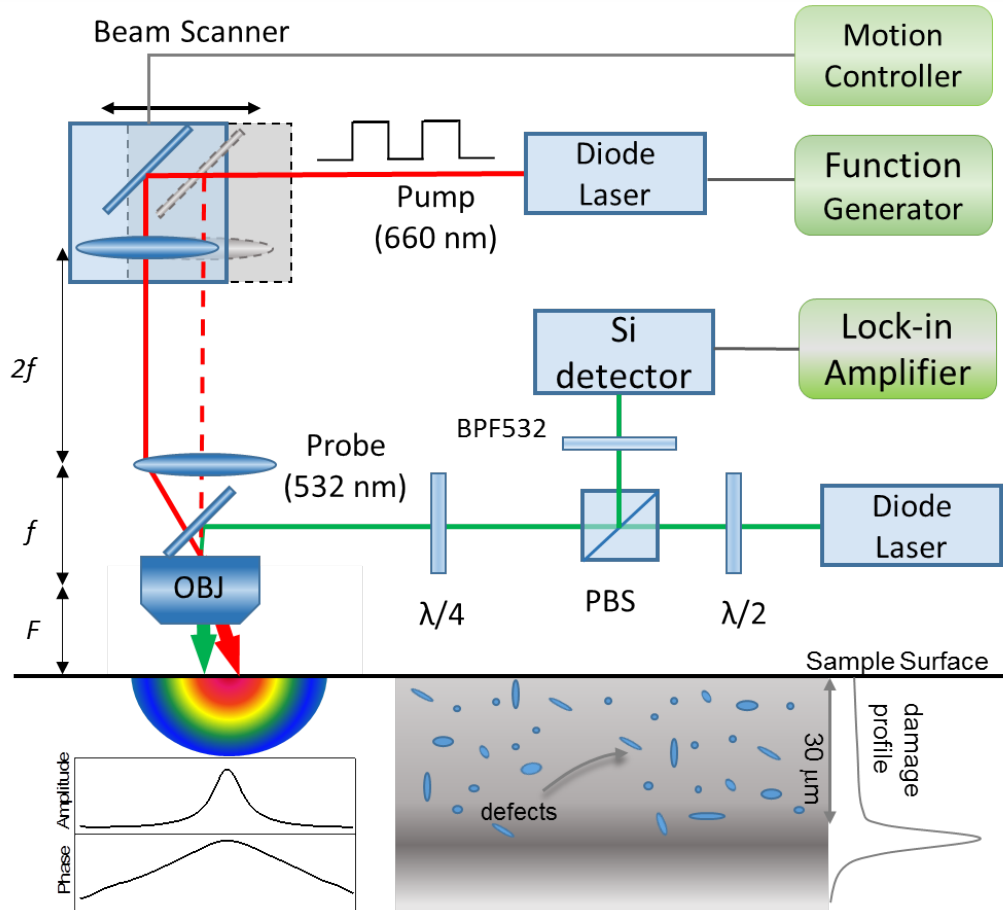


Damage Profile using SRIM

- 2 MeV H⁺ ions at normal incidence
- Total fluence: 8.65×10^{17} ions/cm²
- Kinchin-Pease Method



Laser-based Modulated Thermorefectance Method

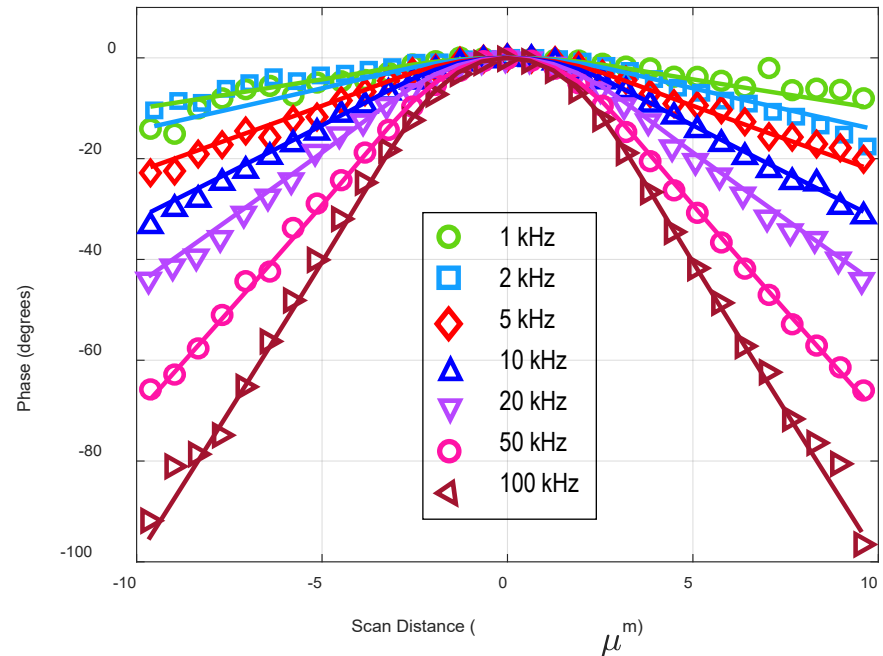
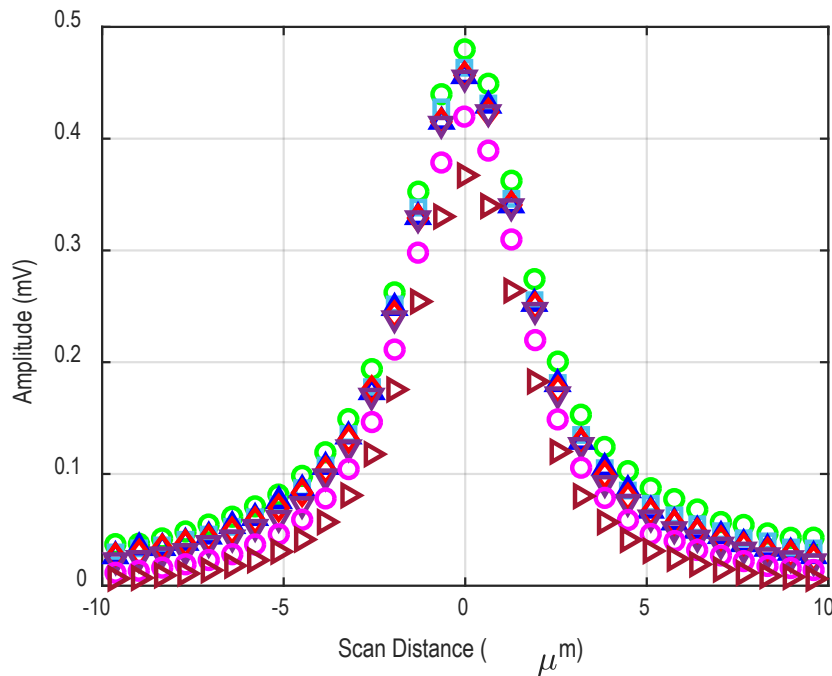


Thermal Wave Diffusion Depth

$$L_D = \sqrt{\alpha / \pi f_0}$$

Thermal Wave Amplitude & Phase Profiles in Pristine ThO₂

Room Temperature Measurements

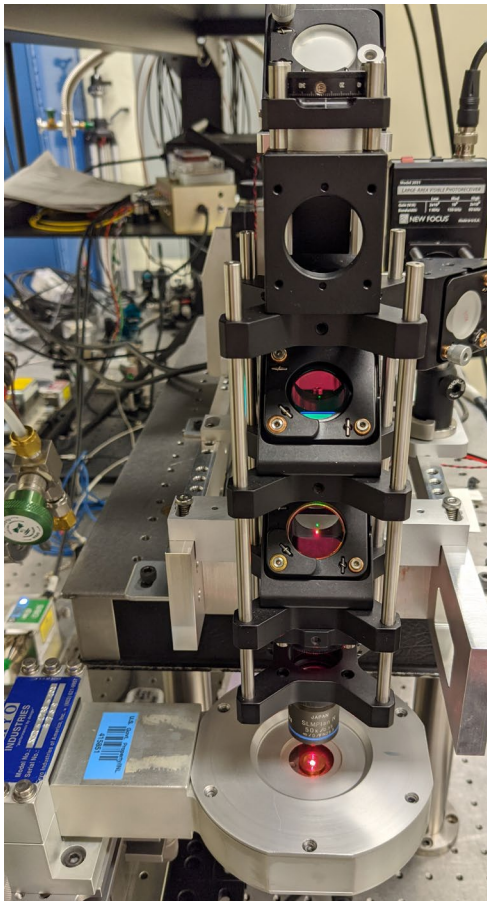


Fitted room temperature thermal diffusivity of pristine ThO₂: $\alpha = 7.66 \pm 0.7 \text{ mm}^2/\text{s}$

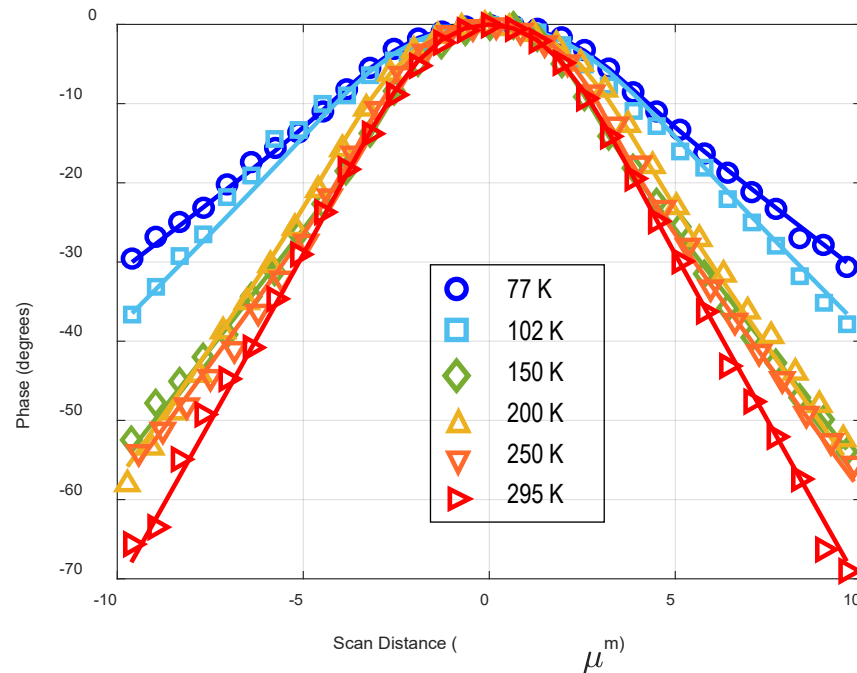
Using room temperature density $\rho = 10.01 \text{ g/cm}^3$ and heat capacity $C_p = 229.1 \text{ J/(kg K)}$, the thermal conductivity of pristine ThO₂ is:

$\kappa = 17.56 \text{ W/(m K)}$

Temperature-dependent Phase Profiles in Pristine ThO_2



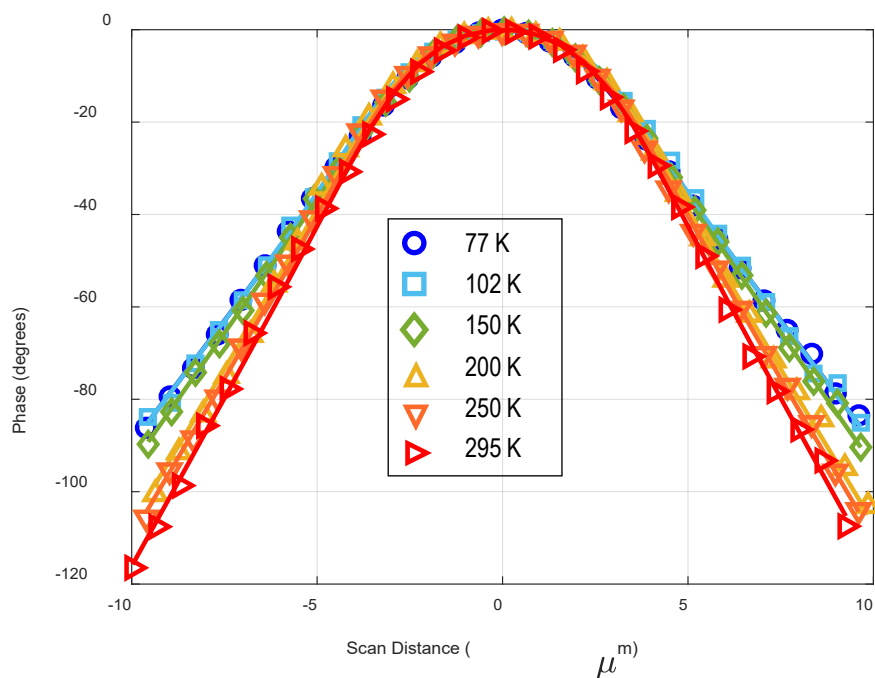
Phase Profiles on Pristine ThO_2
measured from 77 K – 295 K at 50 kHz



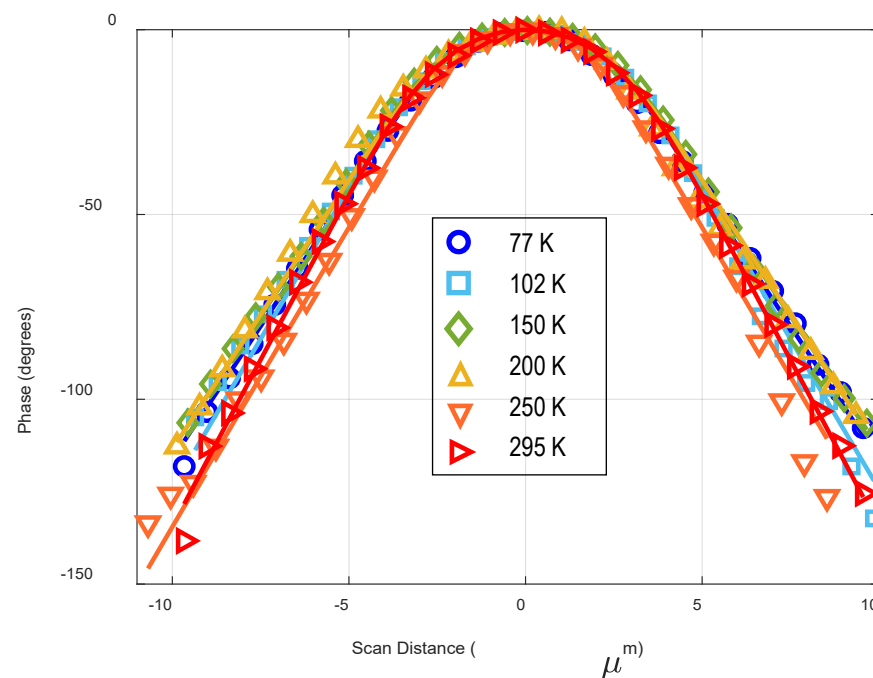
- Phase profiles become more steep with increasing temperature
- Indicates change in thermal diffusivity with temperature

Temperature-dependent Phase Profiles in Irradiated ThO₂

Phase Profiles on 0.01 dpa ThO₂
measured from 77 K – 295 K at 50 kHz

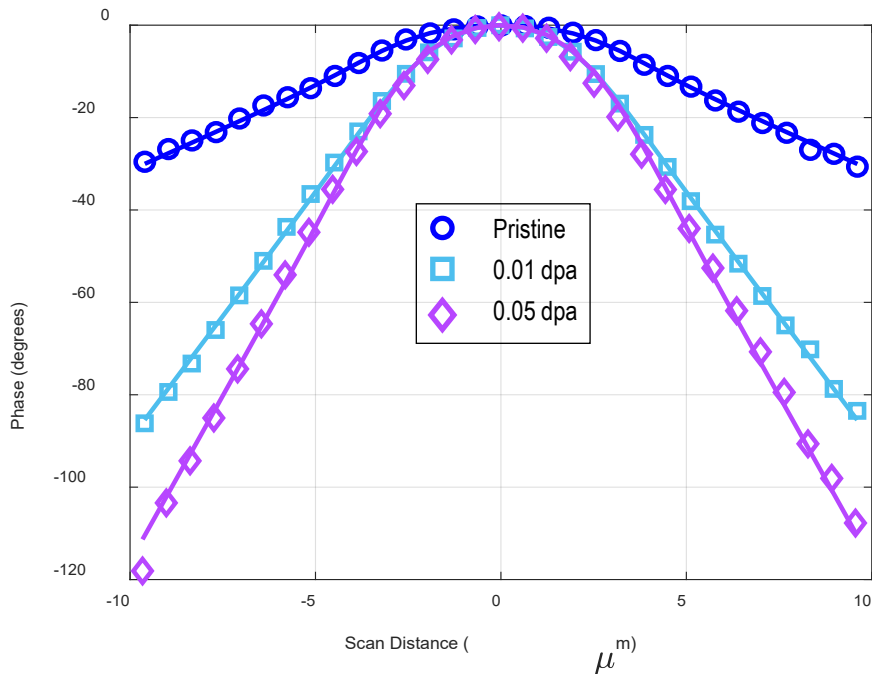


Phase Profiles on 0.05 dpa ThO₂
measured from 77 K – 295 K at 50 kHz

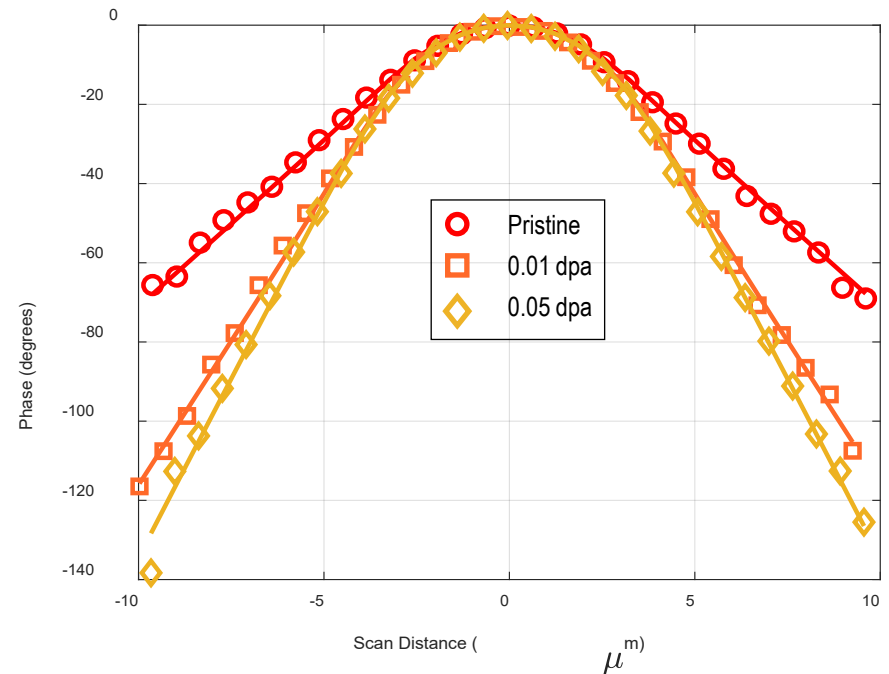


Damage Dose Dependence of Thermal Wave Phase Profiles

Phase Profiles for different damage doses measured at 50 kHz and 77 K

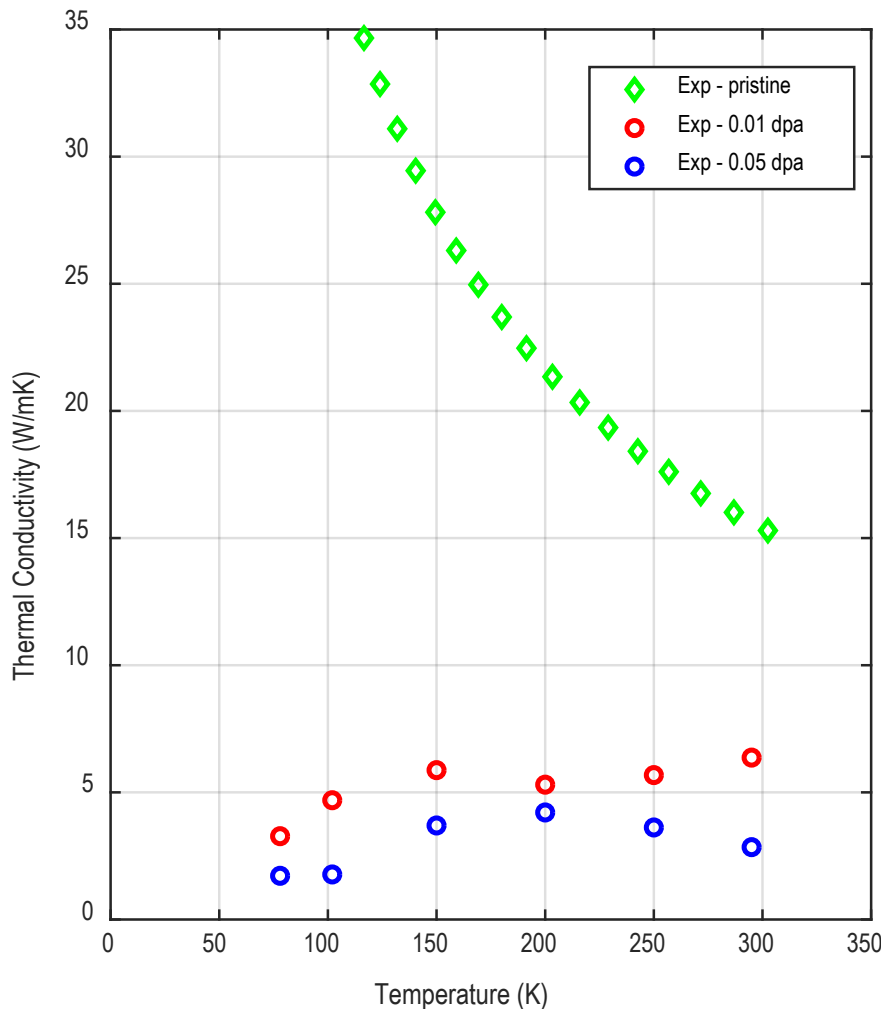


Phase Profiles for different damage doses measured at 50 kHz and 295 K



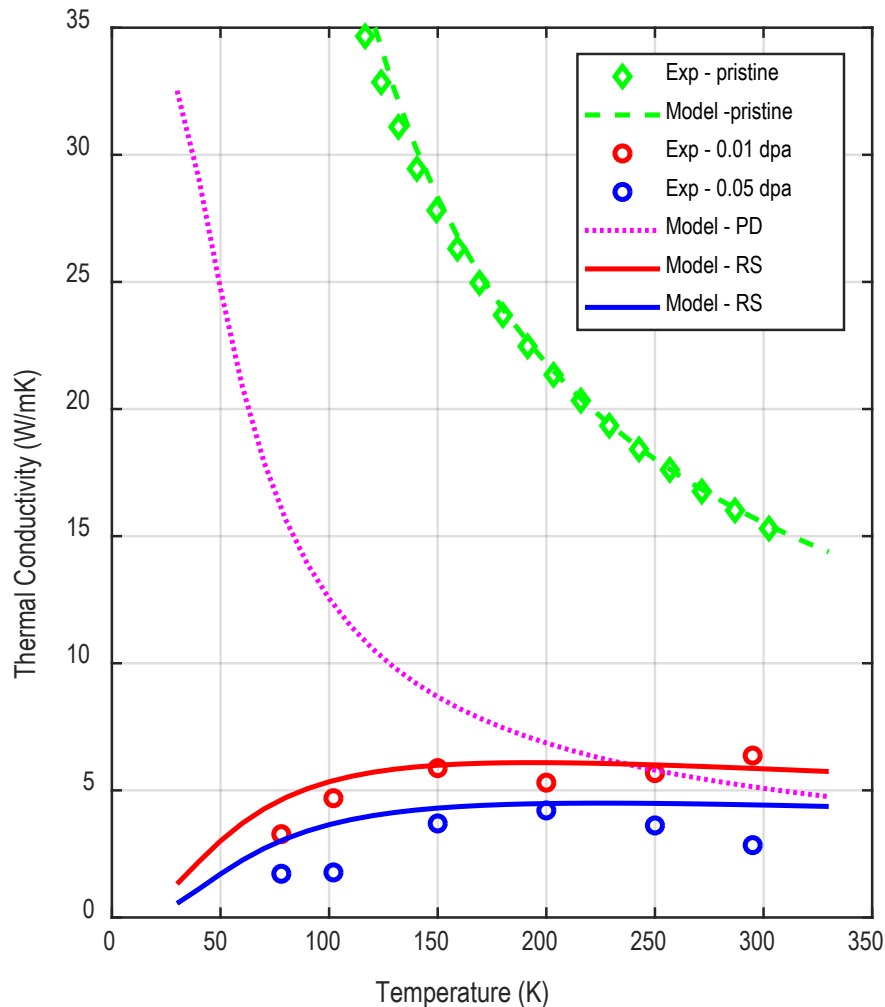
- Phase profiles become steeper with increasing displacement damage
- Change in slope more pronounced at low temperatures

Temperature- and Dose-Dependent Thermal Conductivity



- Reduction in thermal conductivity with temperature in pristine ThO₂ – three-phonon processes mediated by lattice anharmonicity
- Strong influence of irradiation-induced defects - ~60% & ~80% reduction in 0.01 dpa and 0.05 dpa, respectively at room temperature.
- Low temperature dependence in irradiated samples, with slight decrease at lower temperature

Temperature-Dependent Thermal Conductivity using Boltzmann Transport Formalism



BTE with relaxation time approximation:

$$\kappa_0 = \frac{k_B}{2\pi^2 v} \int_0^{\omega_D} \frac{C \omega^2 d\omega}{\tau^{-1}}, \quad C(\omega) = \frac{\hbar^2 \omega^2 e^{\hbar\omega/k_B T}}{k_B T^2 (e^{\hbar\omega/k_B T} - 1)^2}$$

Phonon scattering rate τ^{-1} due to different processes is given by:

$$\tau_{anh}^{-1}(\omega) = B\omega^2 T \quad \text{Lattice anharmonicity}$$

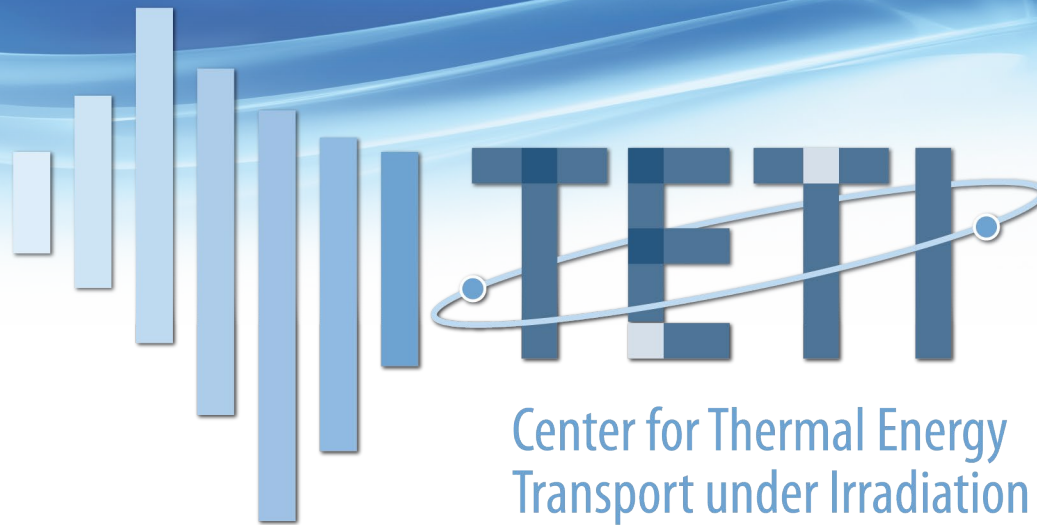
$$\tau_{pd}^{-1}(\omega) = A\omega^4 + B\omega^2 T \quad \text{Isolated point defects}$$

$$\tau_{rs}^{-1}(\omega) = \frac{D}{(\omega - \omega_0)^2 + \Delta\omega^2} + B\omega^2 T \quad \text{Resonant scattering of phonons from quasi-local impurity modes produced by F-centers}$$

- Point defects in irradiated ThO_2 trap electrons and holes that result in resonant phonon scattering
- Existence of shallow hole and deep electrons states is suggested by DFT. Latter is confirmed by optical absorption and photoluminescence measurements

Summary & Conclusions

- Investigated the influence of microstructural defects induced by irradiating single crystal ThO_2 samples with 2 MeV H^+ ions at room temperature
- Irradiation-induced optical absorption peaks suggest formation of F-center defects in crystal lattice
- Spatially-resolved thermal transport measurements performed on the length-scale of microstructural heterogeneity (within the damage layer) using a modulated thermoreflectance approach
- Irradiation-induced damage strongly affects thermal diffusivity/ conductivity – ~83% reduction from pristine to 0.05 dpa at 295 K
- BTE model with scattering rates for different processes shows that resonant scattering from strain fields associated with F-centers
- Future outlook:
 - DFT modeling of electronic transitions will be compared with optical absorption ellipsometry measurements



Center for Thermal Energy
Transport under Irradiation

Acknowledgements

This material is based upon work supported in part by the Center for Thermal Energy Transport under Irradiation, an Energy Frontier Research Center funded by the U.S. Department of Energy, Office of Science, Office of Basic Energy Sciences.



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